

To investigate the optical properties of the As_2S_3 layers in the waveguide regimen were obtained bilayer thin films of Au/As_2S_3 . The thicknesses of the As_2S_3 layers were 125 - 500 nm and bottom layers were Au of thickness 5, 10 and 15 nm respectively. We have compared the optical changes due to the thickness variation of As_2S_3 layer on Au film. The amorphous nature was confirmed by taking by FTIR and XPS techniques. We analyzed the As_2S_3 thin film surfaces and the cross sections obtained by fracture. Figure present a SEM image of the surface of As_2S_3 thin film deposited on Au with a magnification 400000x for 30000 V acceleration voltages. It can see that the nanometric thickness and structure of the surface are uniform and continuous. On the same sample, a scratch procedure was performed in order to measure the thickness of the As_2S_3 thin film in the zones in which fragments of As_2S_3 thin film are perpendicular on the image plane and the thickness is about 160 nm. The thin films have suitable transparency for obtaining optical elements of good quality.

The modulation of the light is enhanced in the amorphous chalcogenide film which is placed in a resonance structure. From reasons of practical applications, the opportunity to use prism with low refractive index such as the BK7 glass were examined, in order to achieve surface plasmonic resonance with waveguide modes. It was obtained the maximum value of the refractive index dispersion about 0.02 of the anisotropy of the refractive index in the range 0.80 μm -0.85 μm optical wavelengths from the refractive index dispersion measurements of As_2S_3 thin films . In the As_2S_3 thin film it is possible to produce a permanent modulation of the optical transmission induced by the pumping laser radiation.

There was investigated optical hysteresis in As_2S_3 thin films that is lead to optical bistability and can lead high-speed signal processing. Fundamental absorption edge is slowly changed in case of thin films and oscillations caused by the interference of light are present in the domain of transparency. The higher the pump beam intensity, the faster changes of the optical transmission may be obtained. This effect may be used for the fabrication of a 2D optical memory cell.

Imaging complex superimposed gratings by digital holographic microscopy

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This paper concerns holographic gratings recording on chalcogenide nanomultilayers (NML) of the composition As_2S_3 -Se. Photosensitive NML of As_2S_3 -Se and constituents films of As_2S_3 , Se were prepared by a computer controlled cyclic thermal vacuum deposition through the mask. The NML sample contained alternating As_2S_3 and Se nanolayers with thickness of each nanolayer of 12 nm. Mass transport phenomenon is the physical process responsible for the formation of the surface relief on this material during interferometric laser inscription.

The relief symmetrical grating is formed directly without additional chemical treatment. The advancement of this paper in comparison to our previous work [1] is the performance of the extra deep surface profile of the diffraction gratings (DG) with a complex hexagonal shape. Two complementary techniques were applied for the surface investigation of the DG: digital

holographic microscopy (DHM) and atomic force microscopy (AFM). For the reconstruction of the grating profile from the interferometric image, an iterative numerical algorithm was used. This hologram processing technique provides significant noise suppression if compared to conventional Fourier Transform based techniques, it was proven in [1, 2]. The determined period of surface relief is $\Lambda=5\mu\text{m}$. The investigated area was $40\mu\text{m} \times 40\mu\text{m}$ that is around 8 periods of the grating. The reconstructed surfaces of the superimposed DG represent regularly spaced hexagonal relief. Both DHM and AFM revealed the symmetrical structure of the modulated relief. Relief depth of hexagonal grating of the polymer film is $1.2\mu\text{m}$.

A major potential application of these particular DG could be the laser wavefront manipulation in a digital holographic microscope (DHM) configuration for collecting more information from the spectrum diffracted by the object under investigation, which generally would drop out of the CCD camera [3-5].

References

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Study of specific heat and Gibb’s free energy of ternary chalcogenide glasses

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In this paper, an effort has been made to study the change in some thermodynamic parameters (say specific heat and Gibb’s free energy) of GeSeIn ternary chalcogenide glasses under non-isothermal conditions. Change in specific heat at glass transition temperature is a characteristics feature of glass. Gibb’s free energy is used as a criterion for glass stability. Gibb’s free energy difference between crystal and glass phase is the